

Fast, vacancy-free climb of dislocation loops in bcc metals

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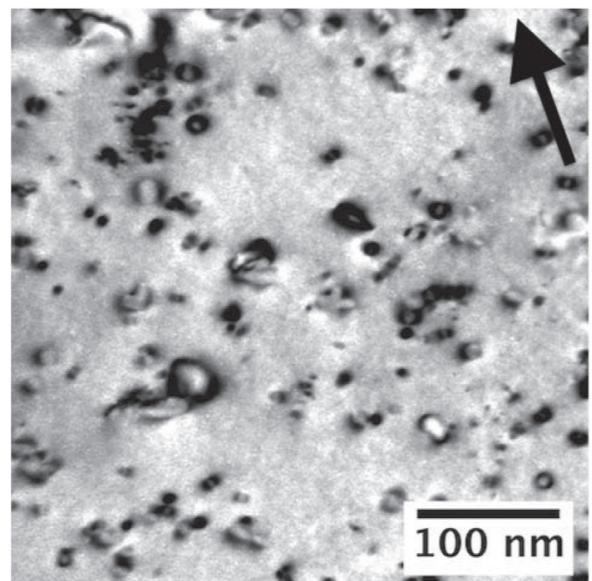
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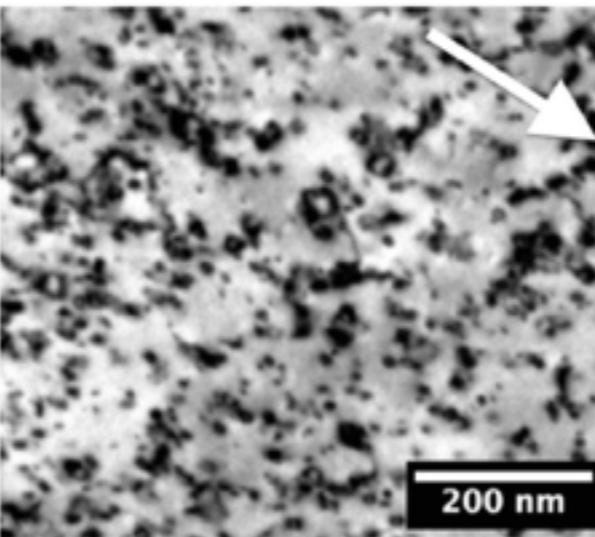
Microstructure Evolution

- Post-irradiation annealing is known to be highly temperature dependent
- The dominant change in microstructure is the growth of prismatic dislocation loops

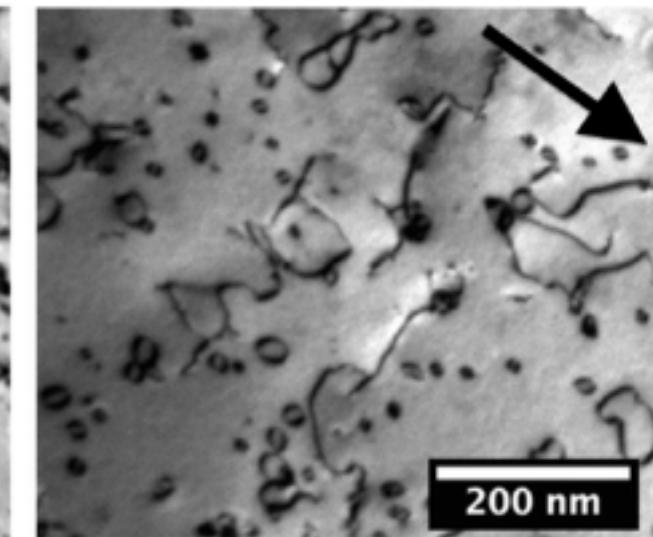


T=1097K, Δt =1 hour T=1097K, Δt =8 hours

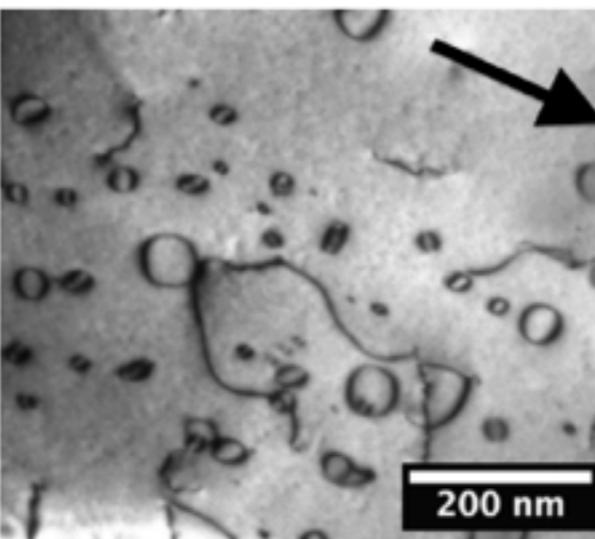
Post-irradiation microstructure after an one hour anneal in tungsten



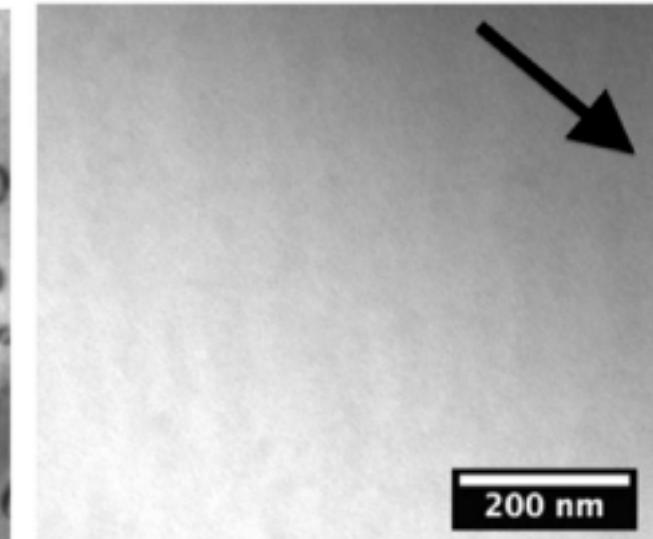
T = 800°C



T = 950°C



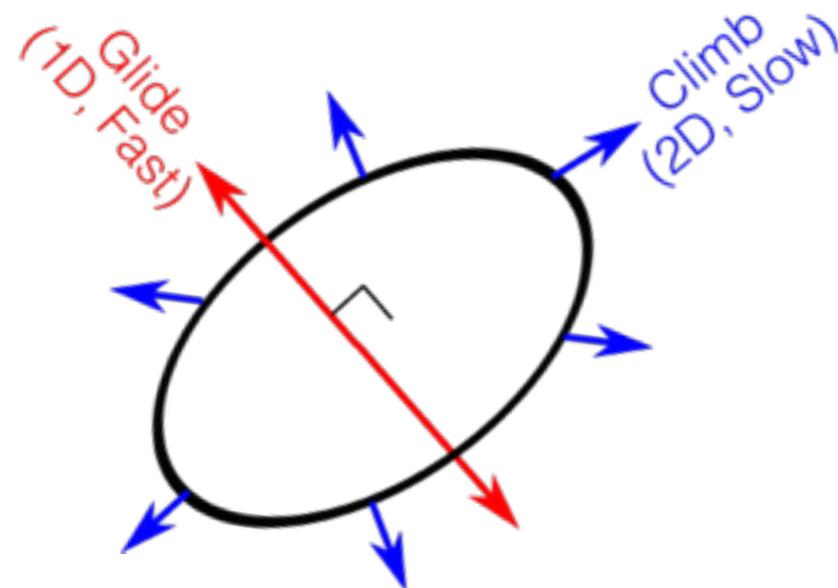
T = 1100°C



T = 1400°C

Climb

- Glide is rapid but often blocked by impurities / junctions etc
- Climb allows dislocations to leave their glide surface even when glide motion is blocked



- Climb typically requires **concurrent mass transport**, facilitated through biased diffusion of the vacancy atmosphere

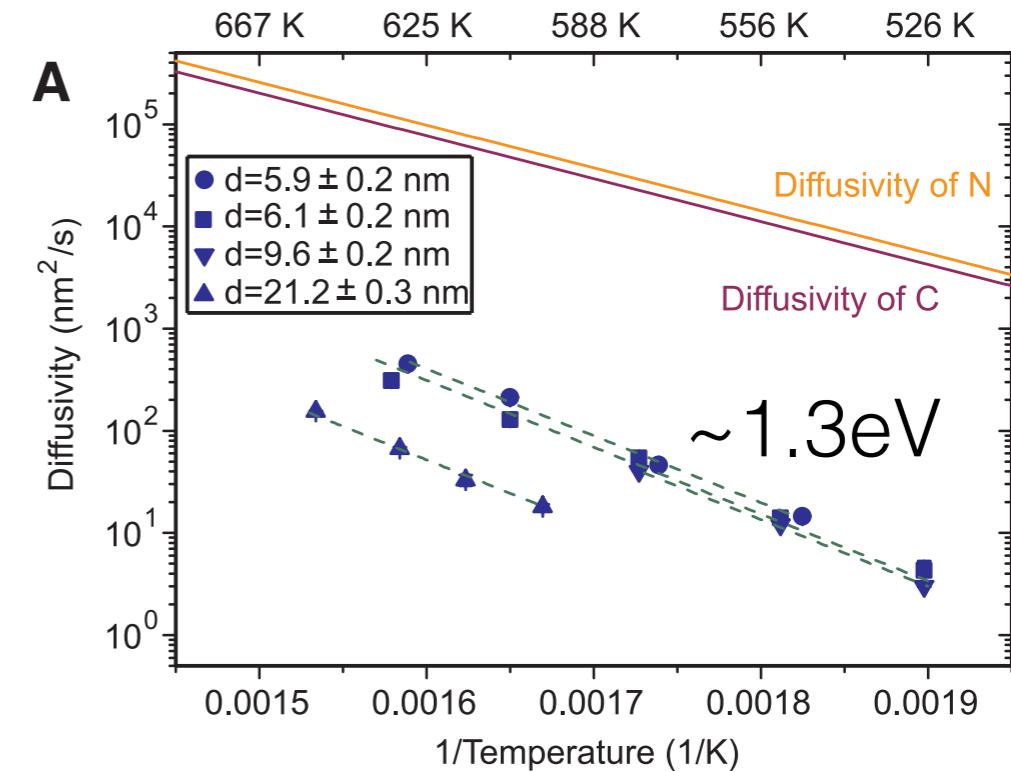


Fig. 4. Diffusivity of almost isolated $\frac{1}{2}\langle 111 \rangle$ loops.

Loop pinning in Fe by C / N
K. Arakawa *et al.* Science 2007

- Theory of **vacancy mediated climb (VMC)** gives

$$V_{VMC} \propto c_{\text{vacancies}} \times V_{\text{vacancy}}$$

$$\propto e^{-\beta(E_{\text{formation}} + E_{\text{migration}})}$$

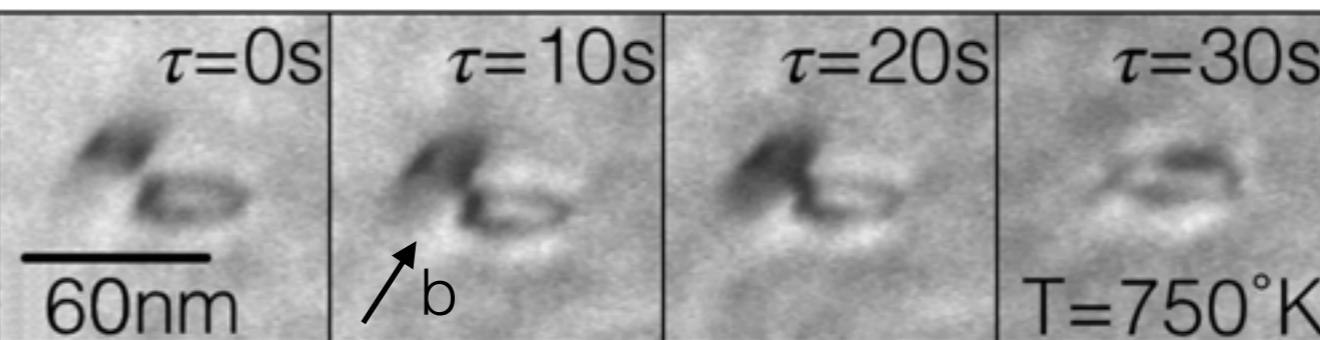
Climb in post irradiation annealing

- Due to the restricted dimensionality of glide, climb has long been known to play an crucial role in PI annealing
- This has been confirmed through direct observation under the TEM
- However, in many experiments climb motion is **up to x10⁶ faster** than the predictions of climb theory

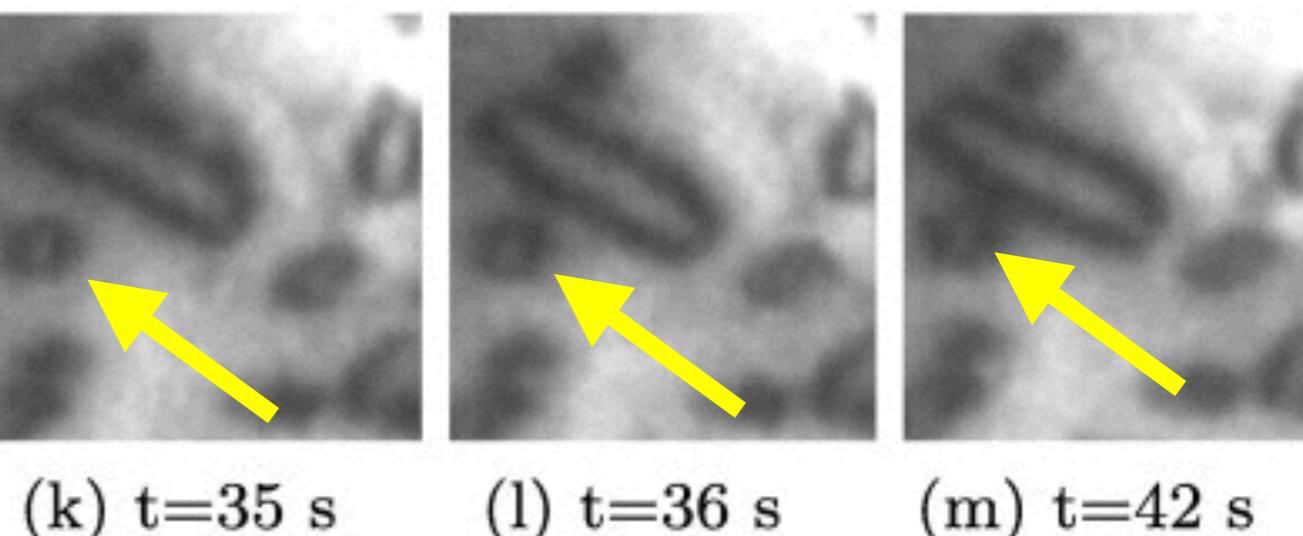
$$v_{VVMC} \propto e^{-\beta(E_{\text{formation}} + E_{\text{migration}})}$$

- In addition, the dislocation loops are actually executing non-glide motion, incompatible with climb theory.

$1/2<111>$ loops in Fe à 750K (this work)



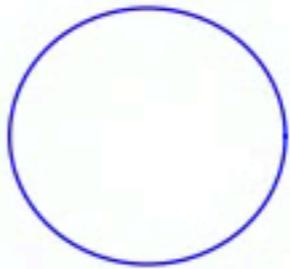
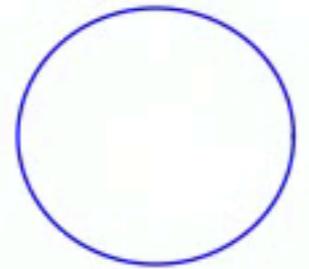
$1/2<111>$ loops in W à 1273K
(Ferroni et al. Acta Met. 2015)



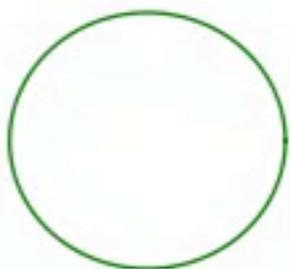
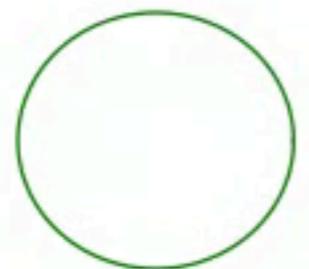
segment separations. For example, at 1200 °C two segments with 1 nm separation would coalesce solely by **vacancy-mediated climb in ~1 h**, making this hypothesis very unlikely based on the experimental observations reported here.

Climb in post irradiation annealing

- Vacancy mediated climb (VMC) is driven by biased diffusion of the surrounding vacancy atmosphere
- This leads to **non-local** coarsening of dislocation loops



VMC Mechanism



TEM Observations

Climb in post irradiation annealing

Feature	Vacancy Mediated Climb (VMC)	Experimental Observations
Loop growth mechanism	Growth by the evaporation of small loops due to non-local vacancy flux balance	Direct coalescence by \neq non-glide motion, with no change in loop area
Rate of climb motion	$\sim 10^{-7} \text{ \AA s}^{-1}$ at $\sim 0.3T_m$	$\ll 10^{0-1} \text{ \AA s}^{-1}$ at $\sim 0.3T_m$

- Vacancy supersaturation (due to e.g. irradiation) can in principle increase the VMC rate, but this cannot account for the mechanism of loop growth
- VMC cannot explain many experimental observations at these temperatures (it is still very important at higher temperatures!)

Climb without vacancies

- This has been recognised since the 1960s, with an alternative mechanism, **self climb**, proposed to allow anomalously fast climb velocities

The Growth of Prismatic Dislocation Loops during Annealing

By C. A. JOHNSON†

Materials Research Laboratory, University of California,
Berkeley, California

[Received June 20, 1960]

C. A. Johnson Phil. Mag. 1960

The Coalescence of Dislocation Loops by Self Climb

By J. A. TURNBULL

Central Electricity Generating Board, Berkeley Nuclear Laboratories,
Berkeley, Gloucestershire GL13 9PB

[Received 15 September 1969]

J. A. Turnbull Phil. Mag. 1970

**Neutron Irradiation Damage in Molybdenum
Part V. Mechanisms of Vacancy and Interstitial Loop Growth
during Post-irradiation Annealing**

By B. L. EYRE and D. M. MAHER†

Metallurgy Division, Atomic Energy Research Establishment, Harwell, Berks.

[Received 6 April 1971]

Eyre and Maher Phil. Mag. 1971

Self-climb of Dislocation Loops in Magnesium Oxide

By J. NARAYAN and J. WASHBURN

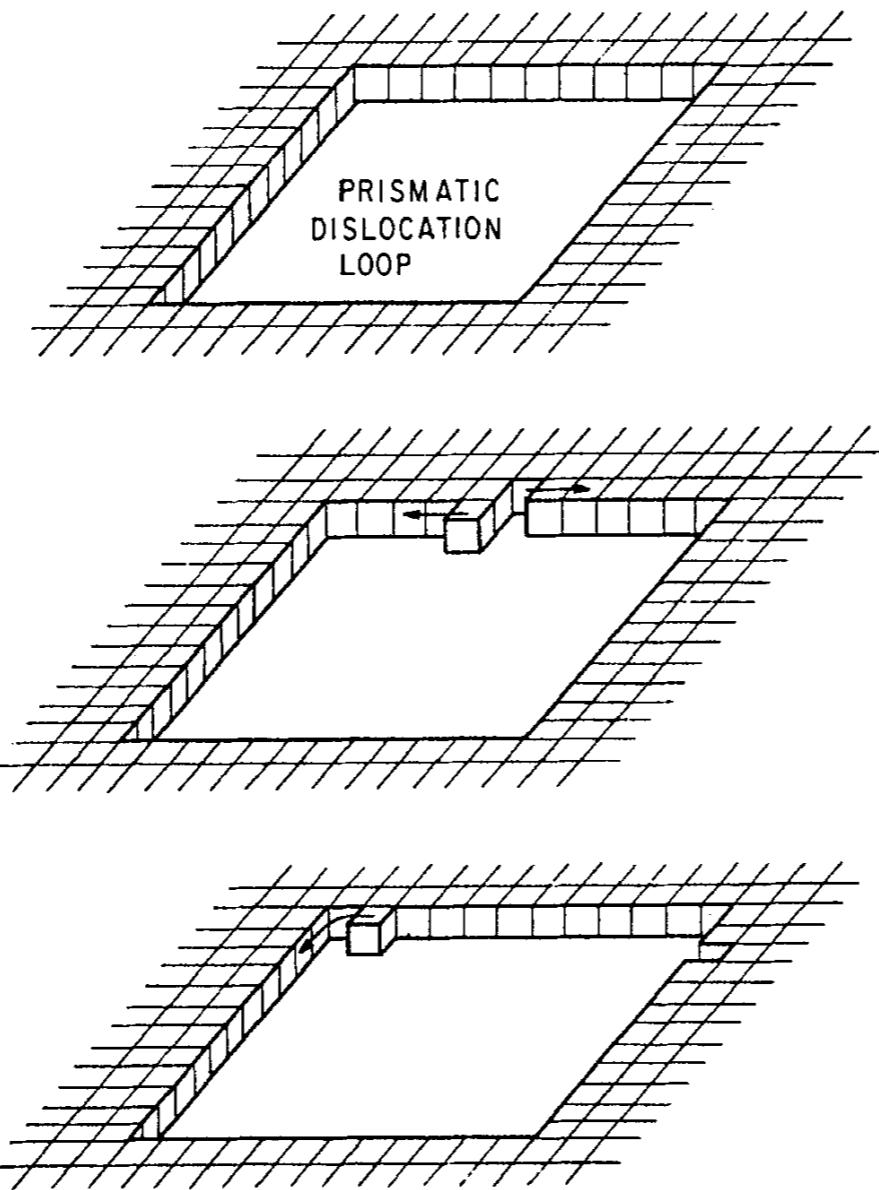
Inorganic Materials Research Division, Lawrence Berkeley Laboratory,
Department of Materials Science and Engineering, College of Engineering,
University of California, Berkeley, California 94720, U.S.A.

[Received 1 February 1972 and in final form 19 June 1972]

Narayan and Washburn Phil. Mag. 1972

Climb without vacancies

- In self climb, non-glide motion is driven through shape fluctuations (i.e. pipe diffusion) around the loop perimeter, much like the transport of surface islands



Formation and migration of defects involved in self-climb.

C. A. Johnson Phil. Mag. 1960

Climb without vacancies

- In self climb, non-glide motion is driven through shape fluctuations (i.e. pipe diffusion) around the loop perimeter, much like the transport of surface islands
- It is simple to derive a self climb mobility -

$$\bar{x} = \sum_i \frac{x_i}{N}, \quad D_{\text{SC}} = \lim_{t \rightarrow \infty} \frac{\langle \bar{x}^2 \rangle}{2t} = \frac{N_P}{N^2} D_P$$

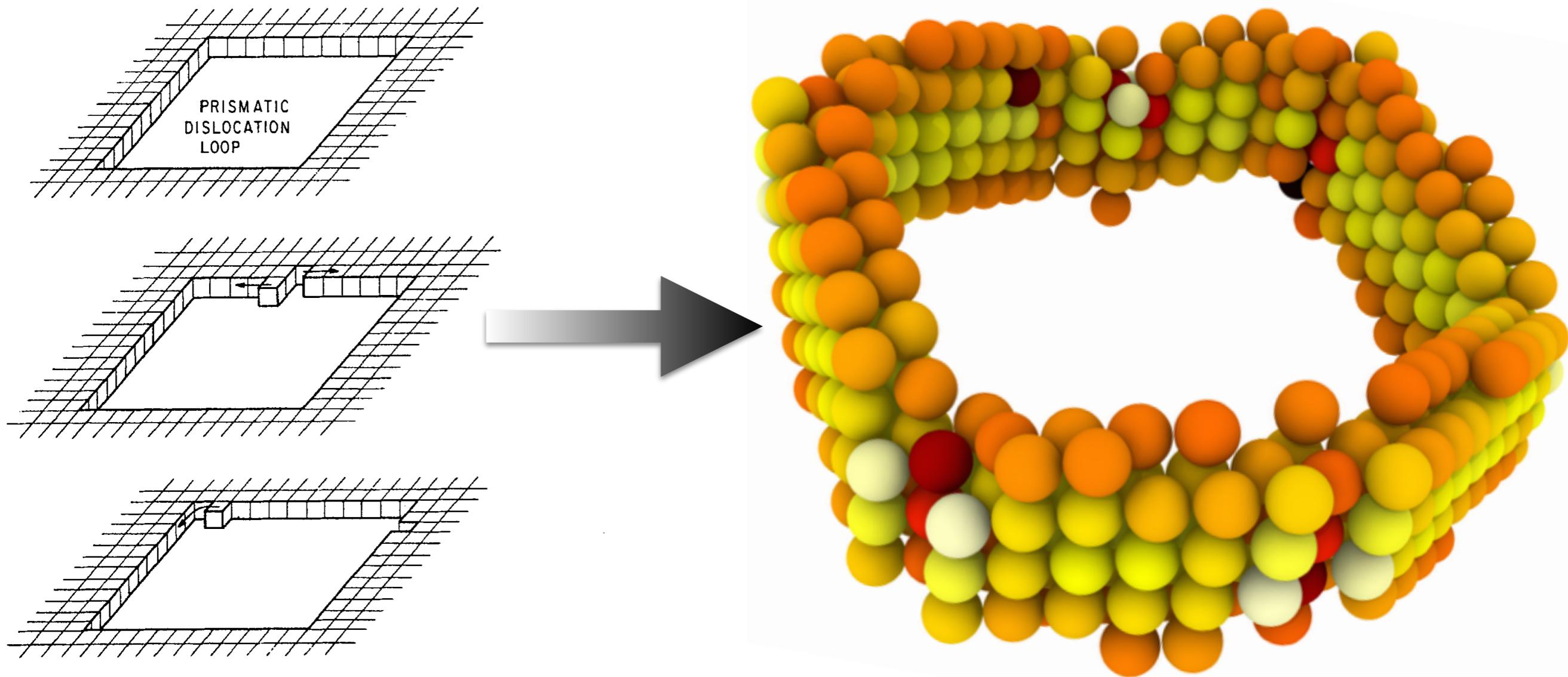
$$\frac{v_{\text{climb}}}{f_{\text{climb}}} \equiv M_{\text{SC}} = \beta D_{\text{SC}} = \frac{2\beta a^5}{\pi R^3} \nu_0 e^{-\beta E_{\text{SC}}}$$

- But all previous studies could not calculate E_{SC} ,
the **critical, rate controlling parameter**
- Previous experiments (in Mo, MgO and Al) found results in the range

$$E_{\text{SC}} \sim (0.4 - 0.7)(E_{\text{formation}} + E_{\text{migration}})$$

Climb without vacancies

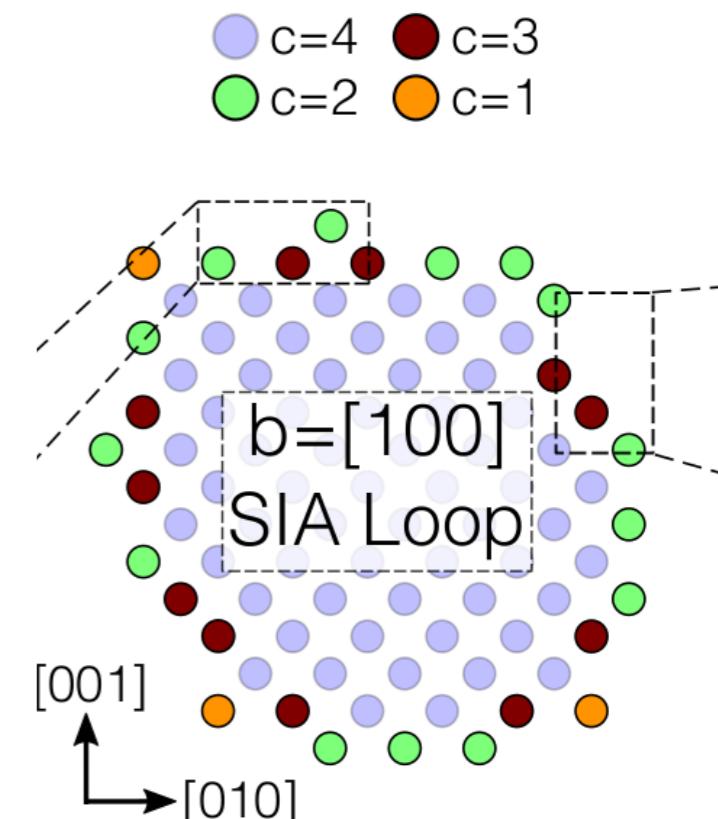
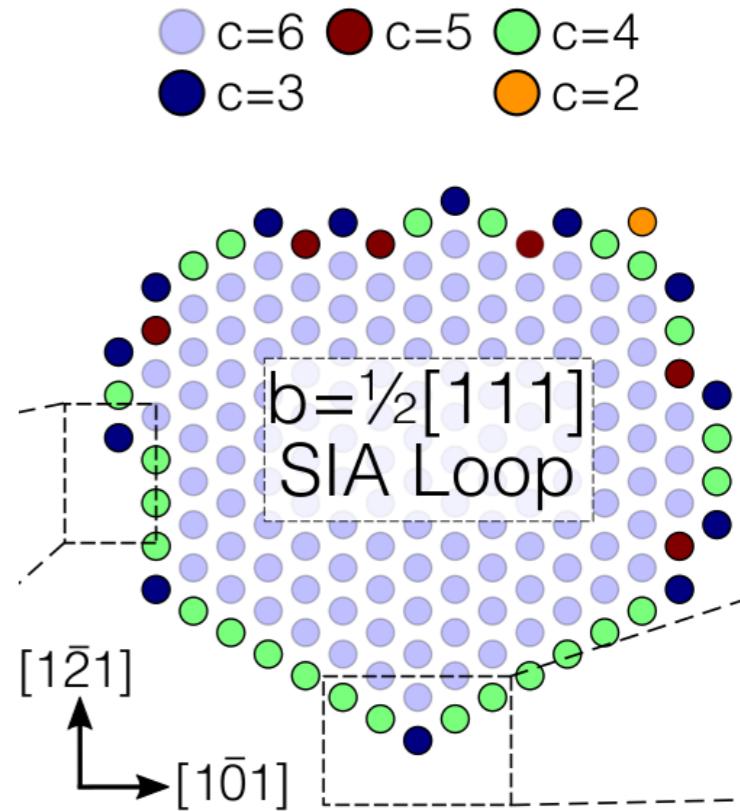
- To calculate a self climb activation energy, we looked at **structural fluctuations** of **irregular** $1/2<111>$ and $<100>$ loops in Fe and W.



- Irregular loops are much more common than regular loops!

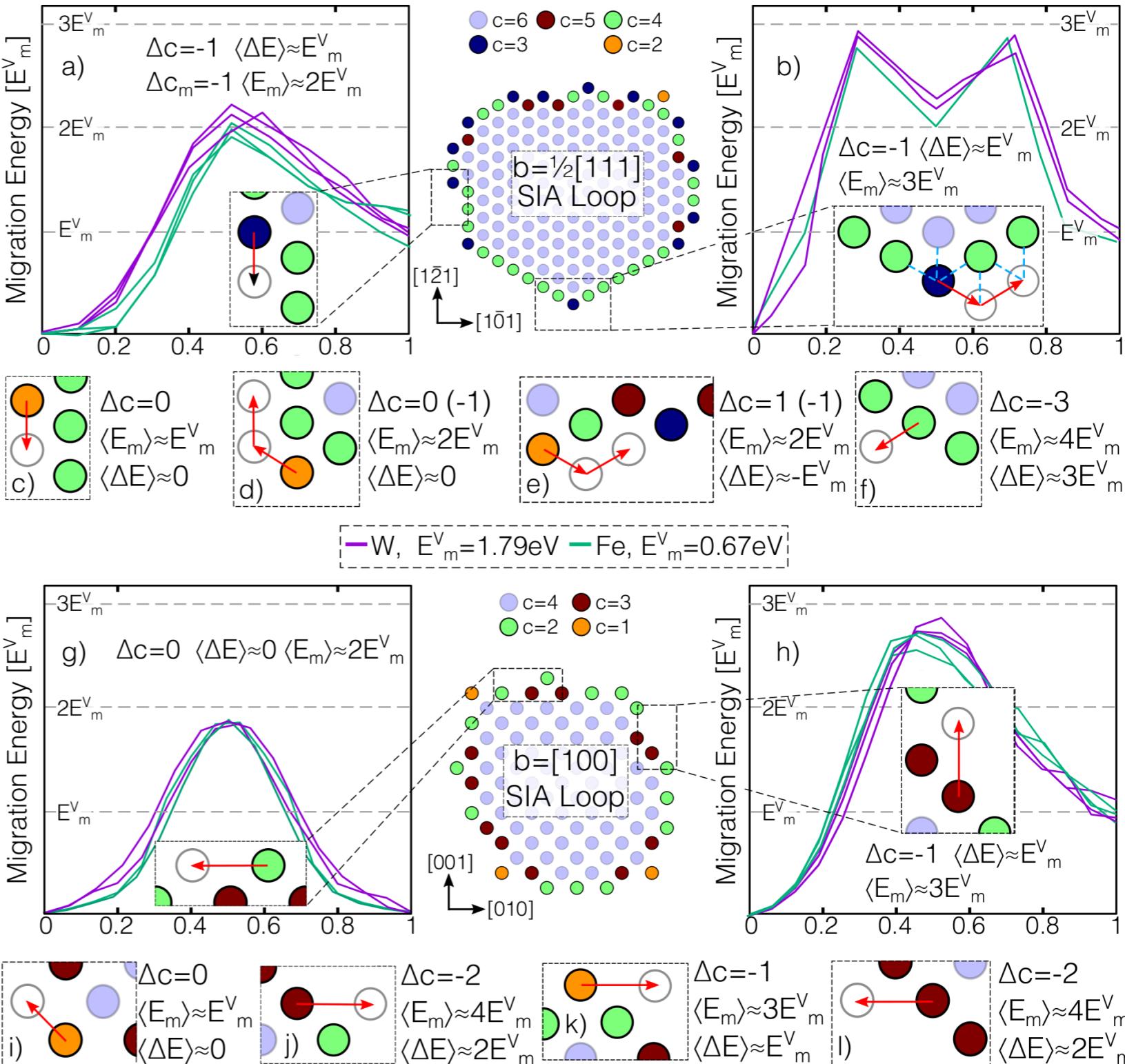
Climb without vacancies

- Automated process written in LAMMPS/Python, using EAM potentials
Fe: Gordon *et al.* Phil. Mag. 2011
W: Marinica *et al.* JPCM 2013
- An irregular SIA palette ($N \sim 170$) is constructed, inserted into a perfect lattice and relaxed
- Possible perimeter fluctuations of the initial palette are identified and then also formed in bulk
- NEB calculation to find migration pathway / barrier
- Identical calculations performed in a two loop supercell to gauge effect of nearby elastic fields
(Answer: less than $\sim 10\%$ even with $d = (2-3)a$)



Climb without vacancies

- All observed pathways could clearly be split into jumps along primitive lattice vectors $1/2\langle 111 \rangle$, $\langle 111 \rangle$, $1/2\langle 111 \rangle$
- The energy barriers in Fe,W could be normalised by the **vacancy** migration barrier



Climb without vacancies

- From 200+ pathways, we found the simple average relation

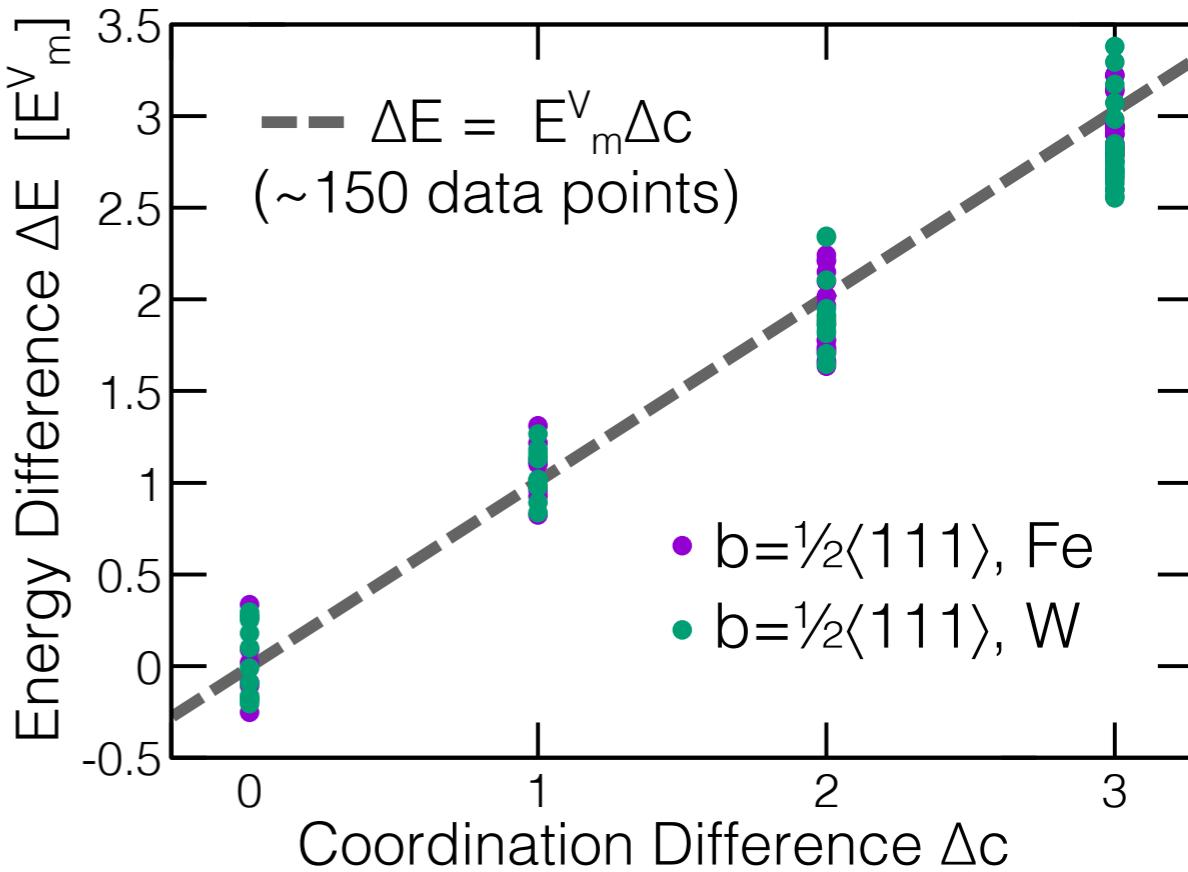
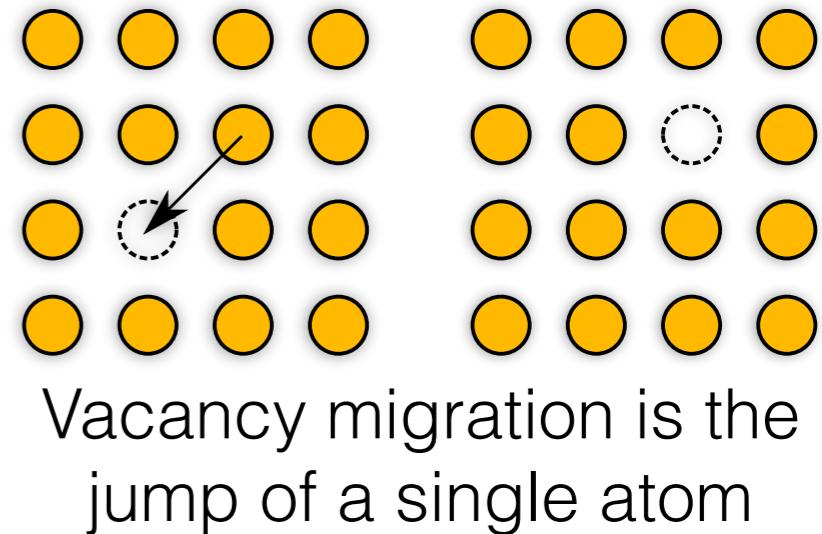
$$\begin{aligned} \text{1/2}\langle 111 \rangle: \Delta E &\simeq \Delta c E_m^V, & E_m &\simeq (\Delta c + 1) E_m^V \\ \langle 100 \rangle: \Delta E &\simeq \Delta c E_m^V, & E_m &\simeq (\Delta c + 2) E_m^V \end{aligned}$$

E_m^V : **vacancy** migration barrier

Δc : change in number of SIA neighbours

$$c_i = \sum_{j \neq i} \Theta\left(\frac{\sqrt{3}}{2}a - |\mathbf{x}_i - \mathbf{x}_j|\right)$$

- The migration of a vacancy is the hopping of a single atom, ‘breaking’ a nn ‘bond’
- For loop fluctuations we have a similar picture, with hops between SIA sites, with a similar **changes** in coordination



Climb without vacancies

$$\Delta E = \Delta c E_m^V$$

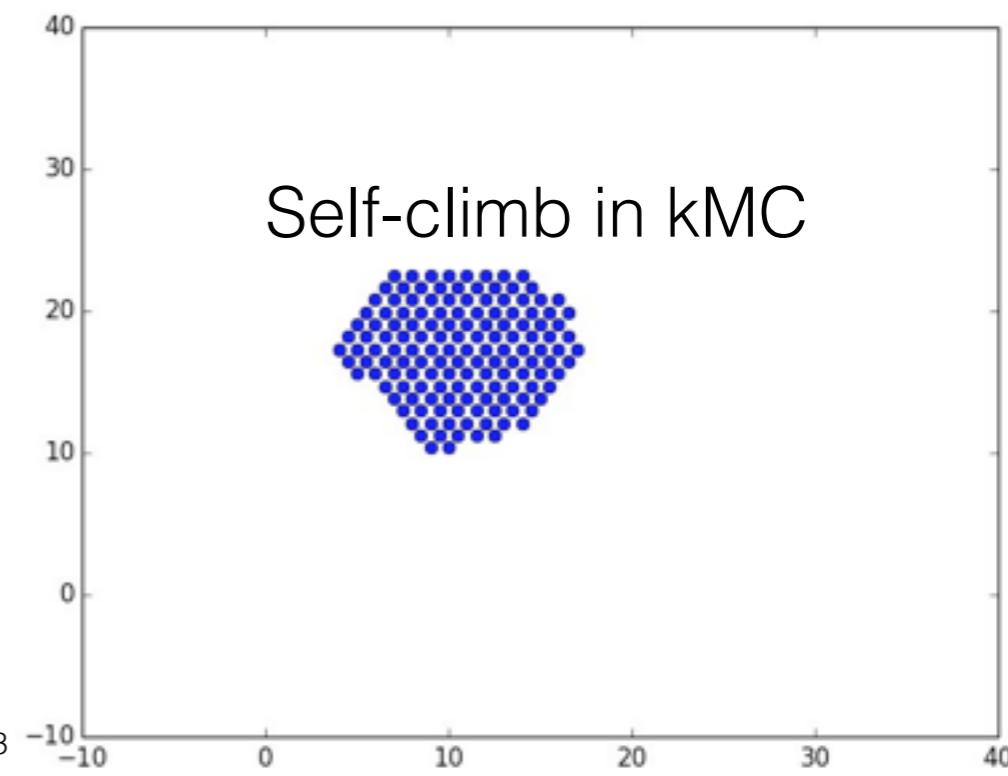
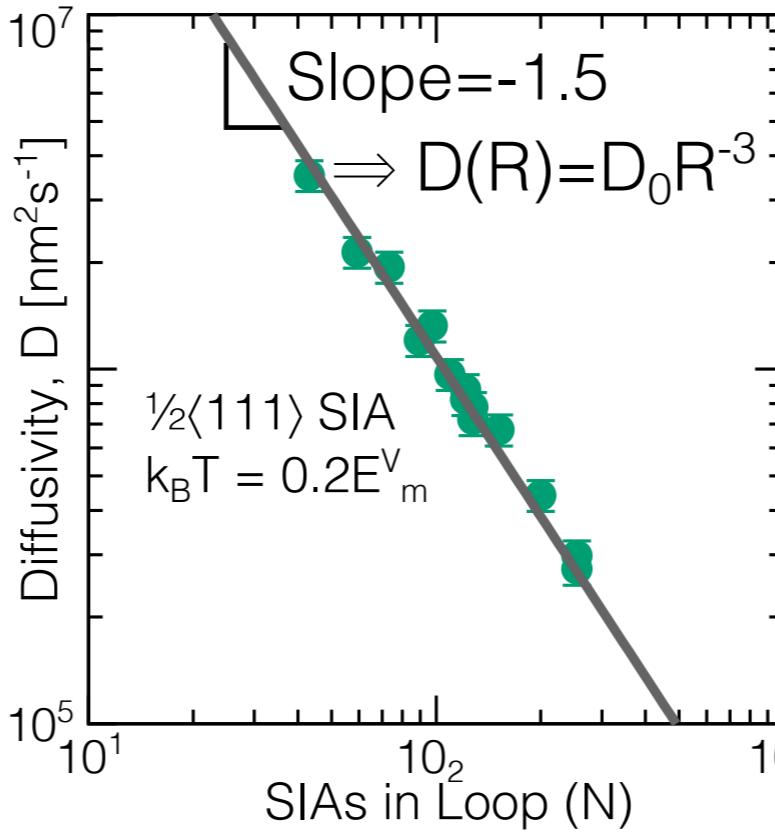
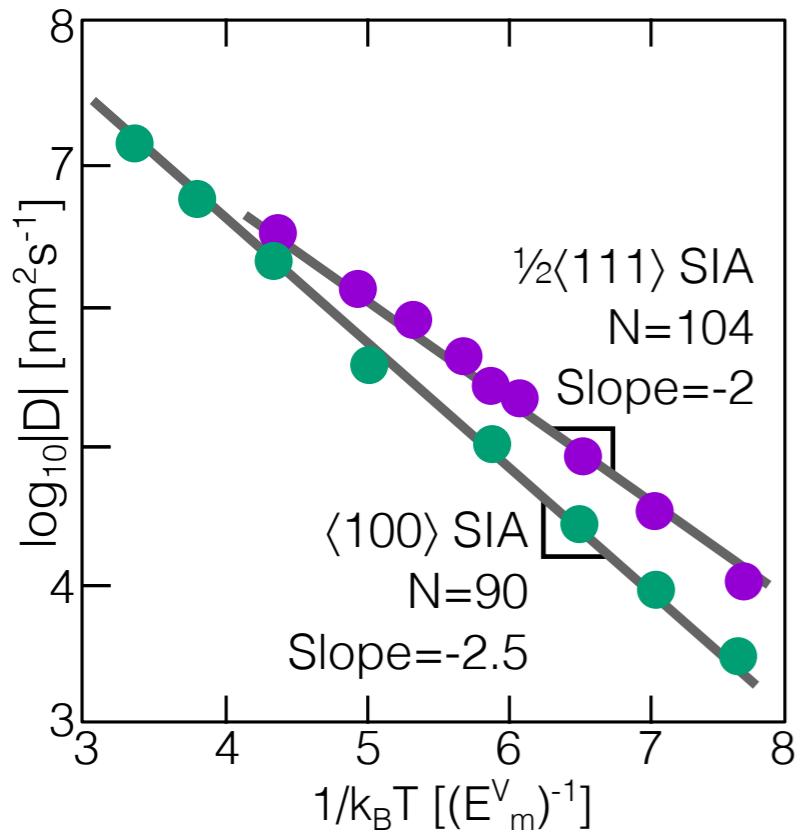
$$E_m^{<111>/2} = (\Delta c + 1) E_m^V$$

$$E_m^{<100>/2} = (\Delta c + 2) E_m^V$$

- Implementing this energy law in kMC we can calculate D_{sc} and therefore E_{sc} , finding that

$$E_{scl}^{<100>} = 2.5 E_m^V, E_{scl}^{1/2<111>} = 2.0 E_m^V$$

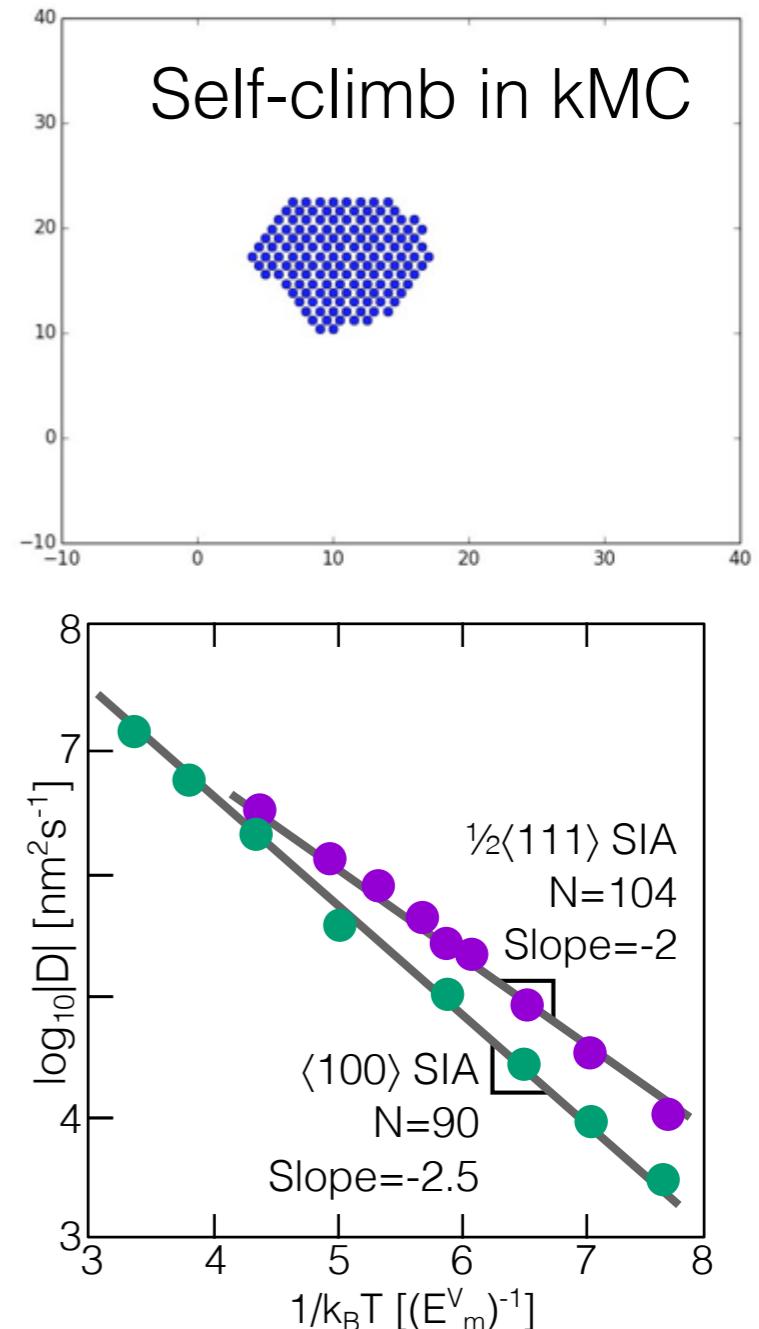
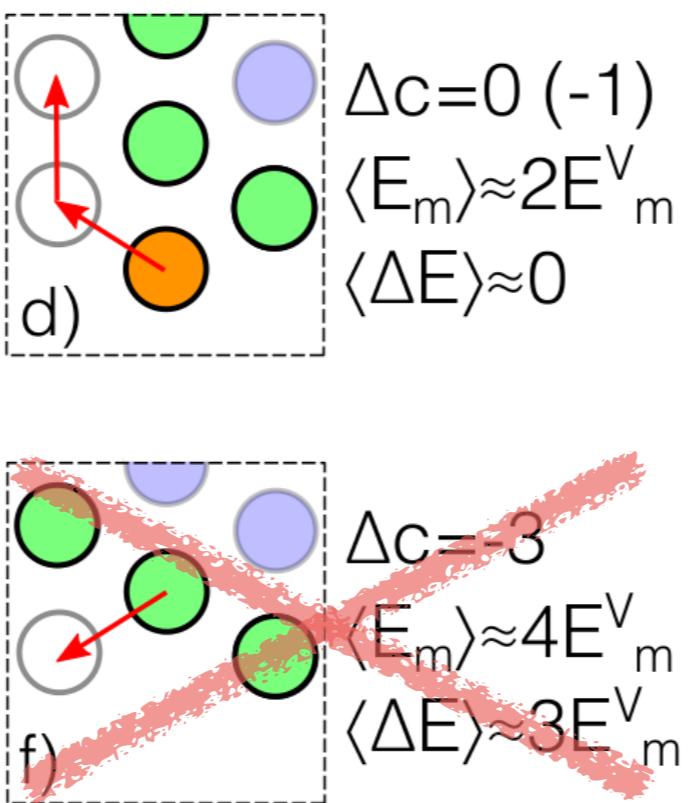
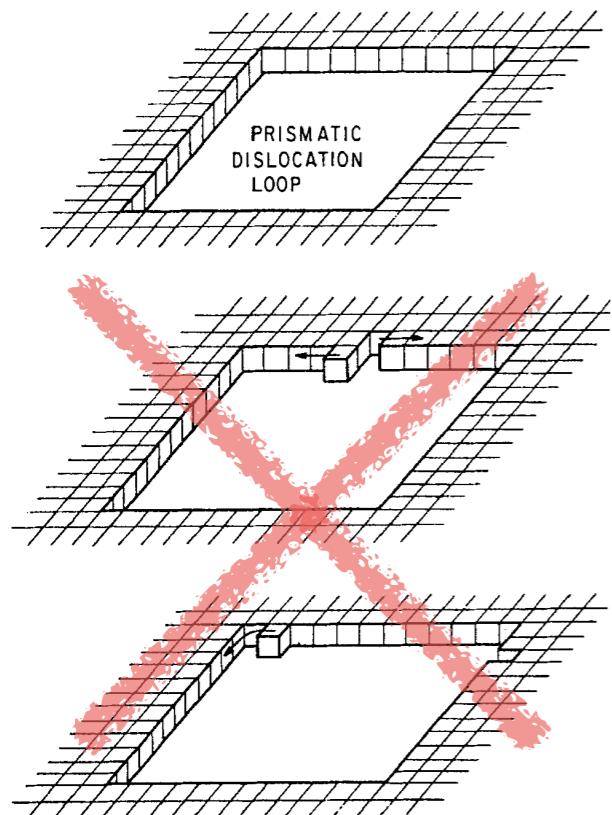
$$M_{scl} = \frac{2\beta\nu a^5}{\pi R^3} e^{-\beta E_{scl}}$$



Climb without vacancies

$$E_{\text{scl}}^{\langle 100 \rangle} = 2.5 E_m^V, E_{\text{scl}}^{1/2\langle 111 \rangle} = 2.0 E_m^V$$

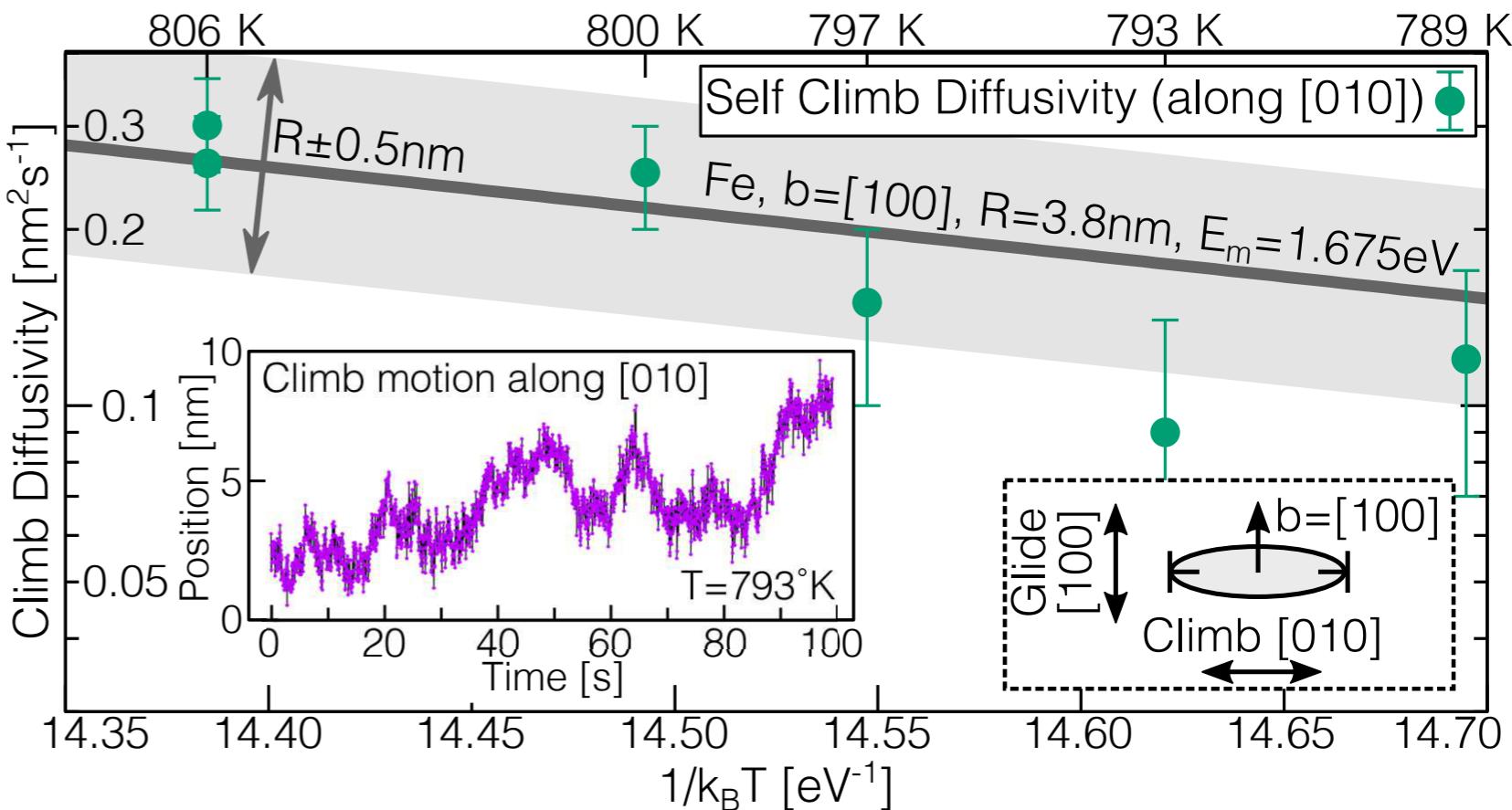
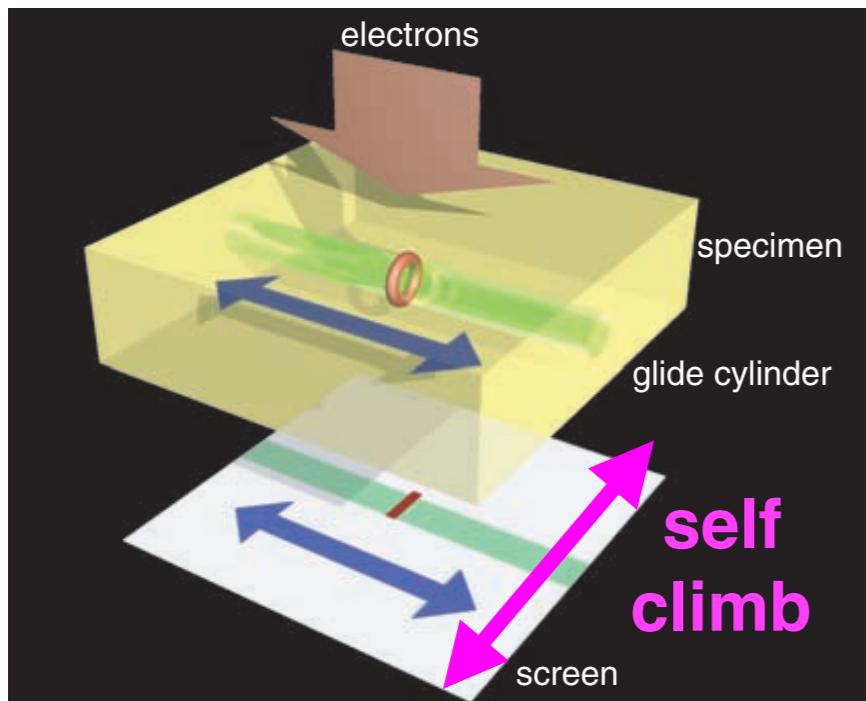
- The activation energy corresponds to SIA migration around loop corners



- D_{scl} is **unchanged** when nucleation from flat surfaces is explicitly forbidden
- Self climb is driven by the **intrinsic roughness** of 'non-magic' number loops

Unbiased self climb diffusion

- In our TEM experiments, essentially isolated prismatic loops were directly observed executing motion perpendicular to the loop Burgers vector



$$M_{\text{scl}} = \frac{2\beta\nu a^5}{\pi R^3} e^{-\beta E_{\text{scl}}}$$

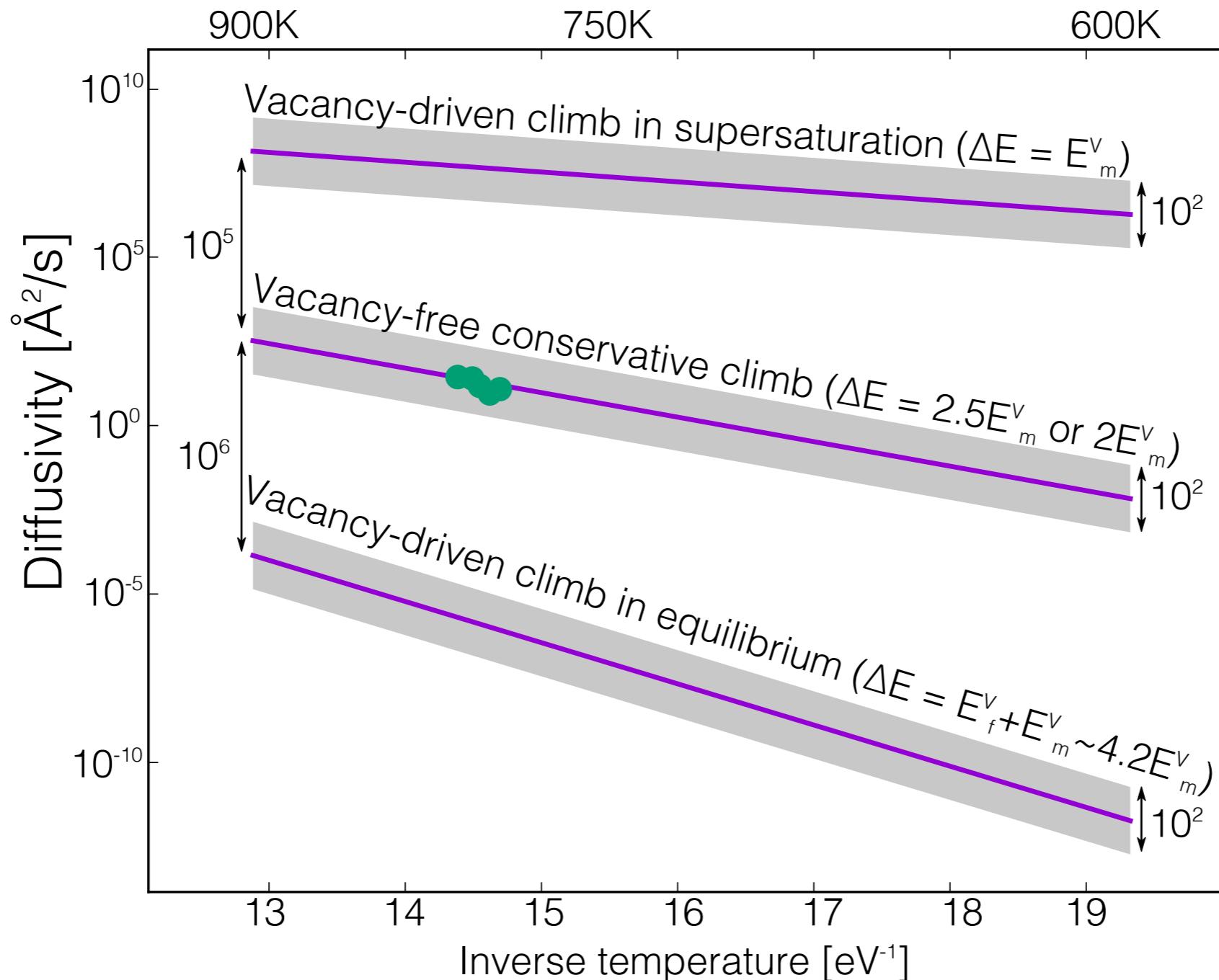
$$E_{\text{scl}}^{\langle 100 \rangle} = 2.5 E_m^V$$

$$E_{\text{VMC}} = 4.2 E_m^V$$

- Our calculated self climb mobility, (with v_0 from DFT, Sandberg *et al.* PRB 2015) gives good agreement with TEM measurements

Other possible mechanisms

- The only other candidates for such non-glide motion, even discarding the migration character, are either too fast or too slow



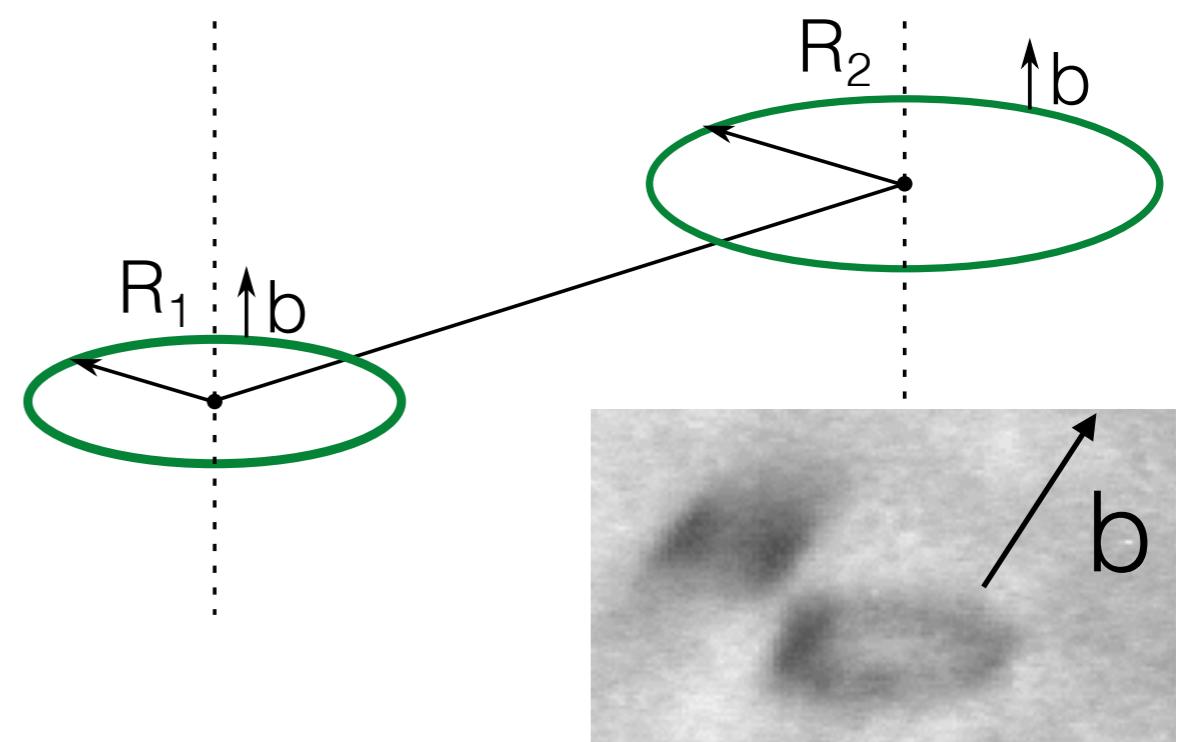
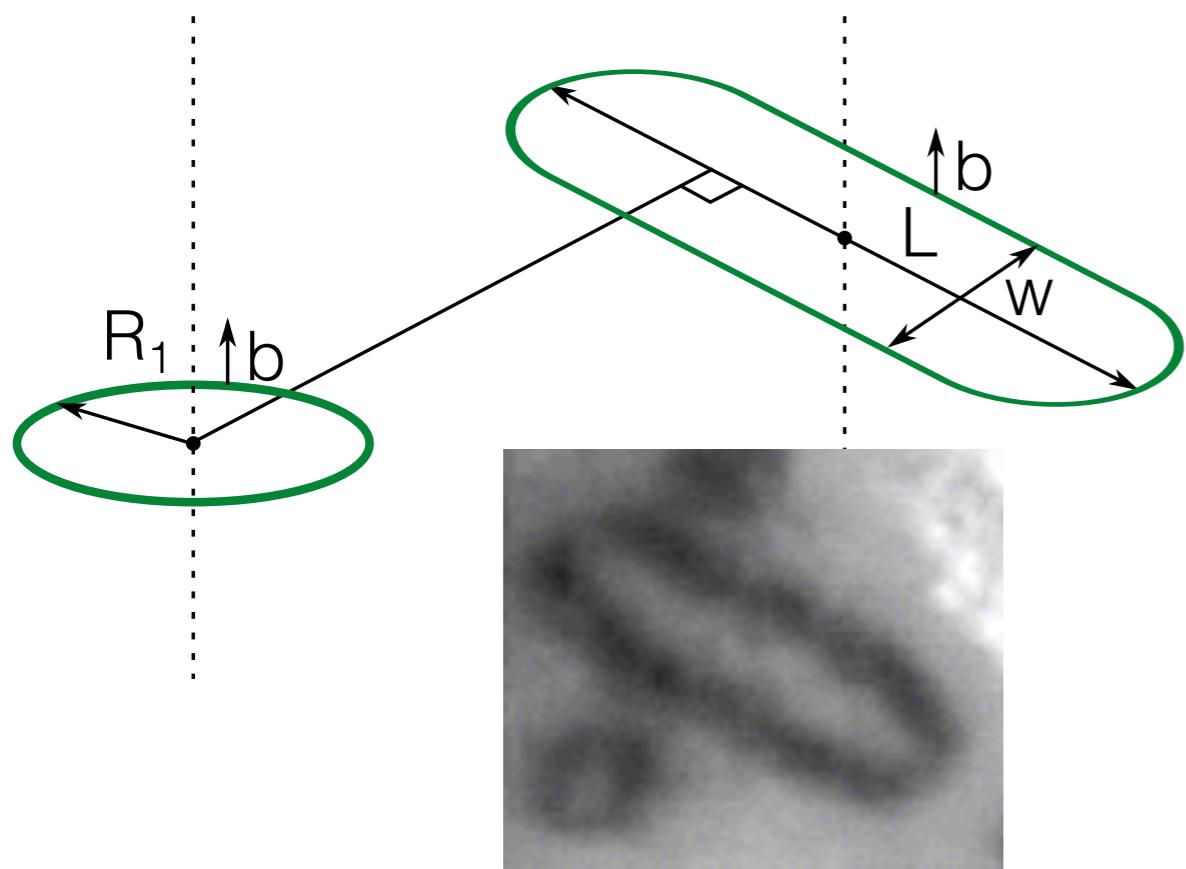
Self climb in DD

- In dislocation dynamics simulations allowing glide and self climb, we emulated binary loop coalescence processes seen under the TEM in Fe and W

$$W_{12} = -\frac{\mu}{2\pi} \oint_{C_1} \oint_{C_2} \frac{(\mathbf{b}_1 \times \mathbf{b}_2) \cdot (d\mathbf{l}_1 \times d\mathbf{l}_2)}{R} + \frac{\mu}{4\pi} \oint_{C_1} \oint_{C_2} \frac{(\mathbf{b}_1 \cdot d\mathbf{l}_1)(\mathbf{b}_2 \cdot d\mathbf{l}_2)}{R}$$

$$+ \frac{\mu}{4\pi(1-\nu)} \oint_{C_1} \oint_{C_2} (\mathbf{b}_1 \times d\mathbf{l}_1) \cdot \mathbf{T} \cdot (\mathbf{b}_2 \times d\mathbf{l}_2) \quad (4-40)$$

$$T_{ij} = \frac{\partial^2 R}{\partial x_i \partial x_j}$$



Self climb in DD

- In dislocation dynamics simulations allowing glide and self climb, we emulated binary loop coalescence processes seen under the TEM in Fe and W

$$\mathbf{f}_{\text{glide}} = -\hat{\mathbf{b}} \otimes \hat{\mathbf{b}} \cdot \nabla E_{\text{elastic}} \quad M_{\text{scl}} = \frac{2\beta\nu a^5}{\pi R^3} e^{-\beta E_{\text{scl}}}$$

$$\mathbf{f}_{\text{climb}} = -\left(1 - \hat{\mathbf{b}} \otimes \hat{\mathbf{b}}\right) \cdot \nabla E_{\text{elastic}} \quad M_{\text{glide}} \gg M_{\text{scl}}$$

$$v_{\text{glide}} = M_{\text{glide}} f_{\text{glide}} \quad v_{\text{climb}} = M_{\text{scl}} f_{\text{climb}}$$

- As $v_{\text{glide}} \gg v_{\text{climb}}$ our simulation protocol is-
 - Let dislocations glide to a steady state due in some time δt_{glide}
 - Calculate $\mathbf{f}_{\text{climb}}$ and find δt_{climb} such that $\delta t_{\text{climb}} |v_{\text{climb}}|^{\max} = (0.1 - 1) \text{\AA}$
 - Update simulation time with $\delta t_{\text{glide}} + \delta t_{\text{climb}}$

Comparison to experiment

- In dislocation dynamics simulations allowing glide and self climb, we emulated binary loop coalescence processes seen under the TEM in Fe and W

$$\mathbf{f}_{\text{glide}} = -\hat{\mathbf{b}} \otimes \hat{\mathbf{b}} \cdot \nabla E_{\text{elastic}}$$

$$\mathbf{f}_{\text{climb}} = -\left(1 - \hat{\mathbf{b}} \otimes \hat{\mathbf{b}}\right) \cdot \nabla E_{\text{elastic}}$$

$$M_{\text{scl}} = \frac{2\beta\nu a^5}{\pi R^3} e^{-\beta E_{\text{scl}}}$$

	$R_1[\text{nm}]$	$R_2[\text{nm}]$	$d[\text{nm}]$	$T[\text{K}]$	$\tau_{\text{exp}}[\text{s}]$	$\tau_{\text{SC}}[\text{s}]$	$\tau_{\text{VMC}}[\text{s}]$
Fe	20	12	30	750	30.0	7.5	3.3×10^7
Fe	3.5	3.5	7	660	~0.8	1.8	2.7×10^7
Fe ^{\$}	~5.	~5.	~10.	725	~6.	2.1	2.7×10^7
W [†]	20	20	100	1173	66.5	96.2	2.6×10^7
W [†]	100	500*	100	1273	7.	8.6	1.5×10^5

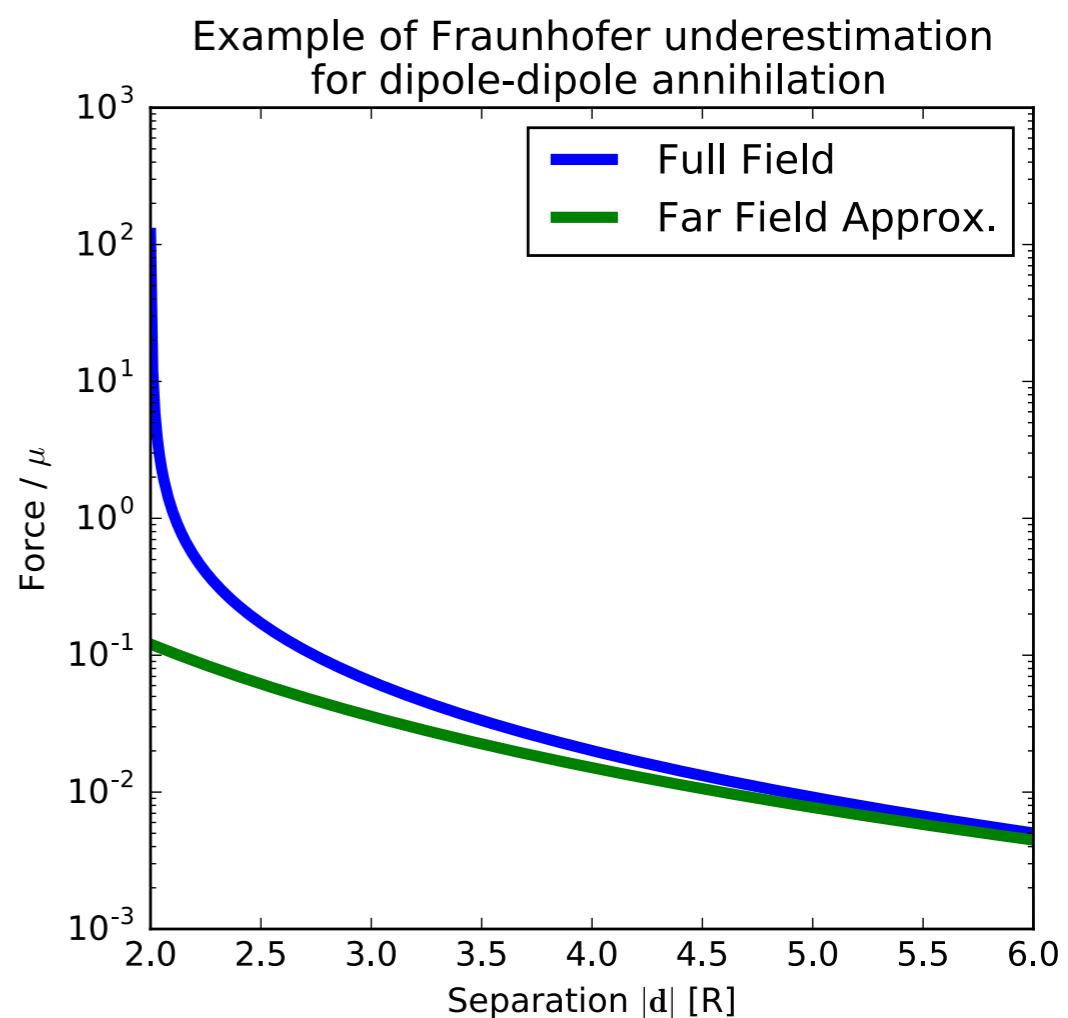
- Hard to find examples that can be modelled with the simplistic dislocation geometry used in simulations but much closer than VMC

Self climb in DD

- We also gauged the influence of self climb in simple DD simulations of post irradiation annealing of a box of ~80 prismatic $1/2<111>$ loops in Fe at 750K
- For computational simplicity we used the far field approximation ($R \ll d$) for parallel loop-loop interaction

$$-\nabla E_{\text{elastic}}^{12} = \frac{\mu b^2 \pi^2 R_0^2 R_1^2}{4\pi(1-\nu)|\mathbf{d}|^4} \left(g(\theta) \hat{\mathbf{d}} - f(\theta) \hat{\mathbf{b}} \right)$$

- This approximation does not capture the force divergence and hence **underestimates** self-climb driven coalescence rates.

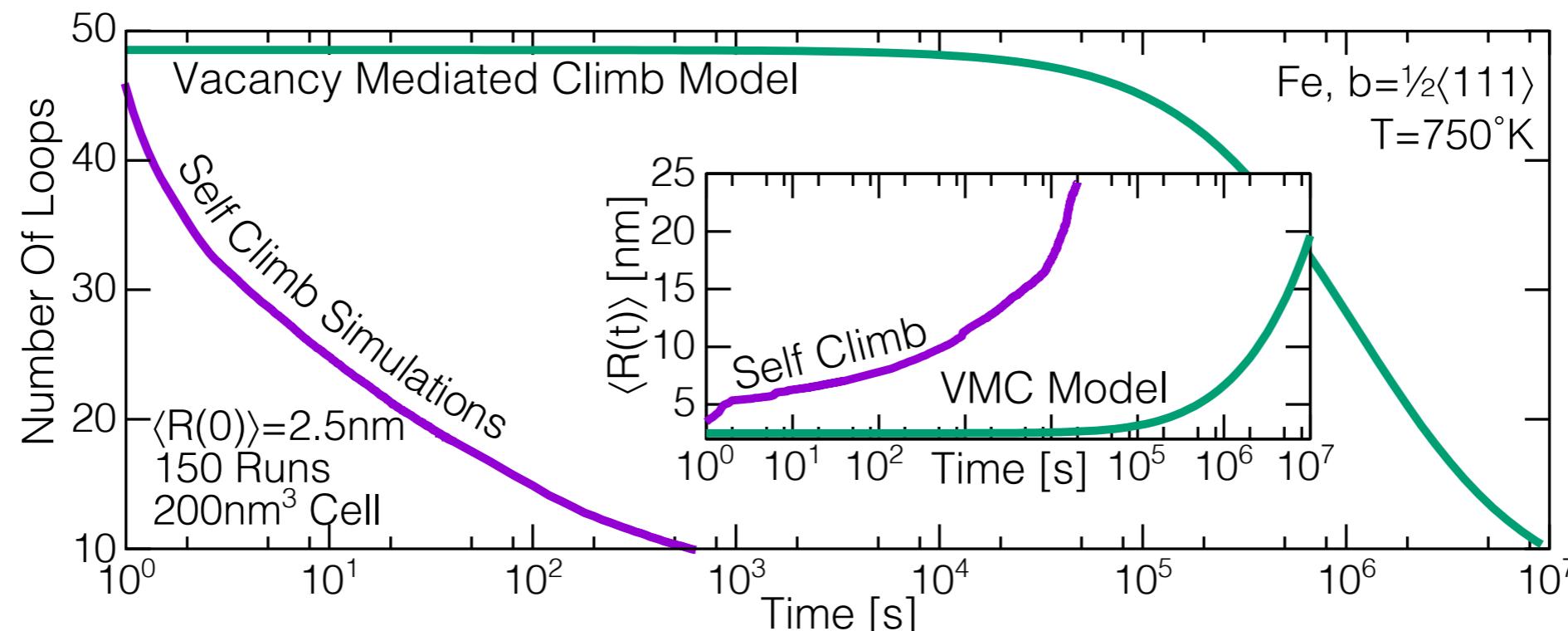


Self climb in DD

- We also gauged the influence of self climb in simple DD simulations of post irradiation annealing of a box of ~80 prismatic $1/2\langle 111 \rangle$ loops in Fe at 750K
- Compared against an analytical model of vacancy mediated climb driven annealing, which has been successfully tested with VMC climb simulations

$$N_{\text{loops}}(t) = \frac{N_{\text{loops}}(0)}{1 + \alpha t} \quad \alpha = \frac{\beta \mu \Omega}{\langle R_{t=0}^2 \rangle} e^{-\beta(E_{\text{formation}} + E_{\text{migration}})}$$

- Bakó, Clouet, Dupuy and Blétry Phil. Mag. 2011
- In agreement with experiment, self climb significantly affects PI annealing rates



Outlook / Conclusions

- By considering structural fluctuations on timescales too great for MD, anomalously fast defect coalescence can be accurately modelled.

TDS, K Arakawa, *et al.*, *Scientific Reports* 2016

- Self climb is fast due to the significantly lower activation energy

$$\text{Self-Climb: } E_{\text{SC}} = (2 \text{ or } 2.5)E_m^V \quad E_f^V + E_m^V \simeq 4E_m^V \quad (\text{Fe})$$

$$\text{Climb: } E_m^V + E_f^V \simeq (3 - 5)E_m^V \quad E_f^V + E_m^V \simeq 3E_m^V \quad (\text{W})$$

- Consistent with previous experiments that found $E_{\text{SC}} = (0.4 - 0.7)(E_f^V + E_m^V)$
- Inclusion of self climb mobilities, benchmarked against experiments, has a significant influence on the rate of post-irradiation annealing simulations
- Future work will investigate the proven role of self climb in post-irradiation annealing and explore applications to climb motion of dislocation lines

Thank you for listening

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tiny.cc/tds110